

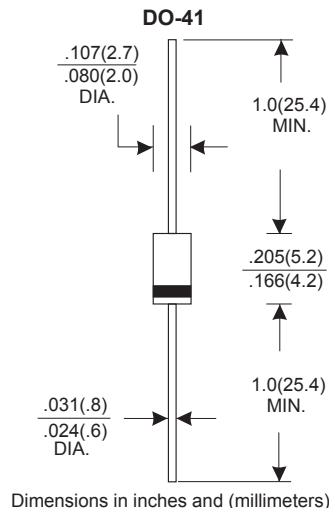
1.0 AMP SILICON RECTIFIERS

Features:

- * Low forward voltage drop
- * High current capability
- * High reliability
- * High surge current capability

Mechanical Data:

- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: Axial leads, solderable per MIL-STD-202, method 208 guranteed
- * Polarity: Color band denotes cathode end
- * Mounting position: Any
- * Weight: 0.34 grams
- * Both normal and Pb free product are available:
- * Normal: 80~95%Sn, 5~20%Pb
- * Pb free: 99 Sn above can meet Rohs enviroment substance directive request



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unieess otherwies specified.
 Single phase half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

TYPE NUMBER	EM513	EM516	EM518	UNITS
Maximum Recurrent Peak Reverse Voltage	1600	1800	2000	V
Maximum RMS Voltage	1120	1260	1400	V
Maximum DC Blocking Voltage	1600	1800	2000	V
Maximum Average Forward Rectified Current				
.375"(9.5mm) Lead Length at Ta=75°C	1.0			A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	30			A
Maximum Instantaneous Forward Voltage at 1.0A	1.1			V
Maximum DC Reverse Current Ta=25°C	5.0			μA
at Rated DC Blocking Voltage Ta=100°C	50			μA
Typical Junction Capacitance (Note 1)	15			pF
Typical Thermal Resistance RθJA (Note 2)	50			°C/W
Operating and Storage Temperature Range Tj, Tstg	-65 — +150			°C

NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Thermal Resistance from Junction to Ambient .375" (9.5mm) lead length.

RATING AND CHARACTERISTIC CURVES

FIG.1-TYPICAL FORWARD CHARACTERISTICS

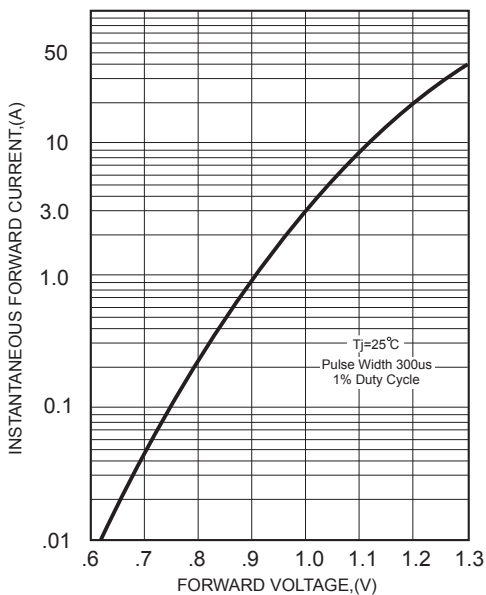


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

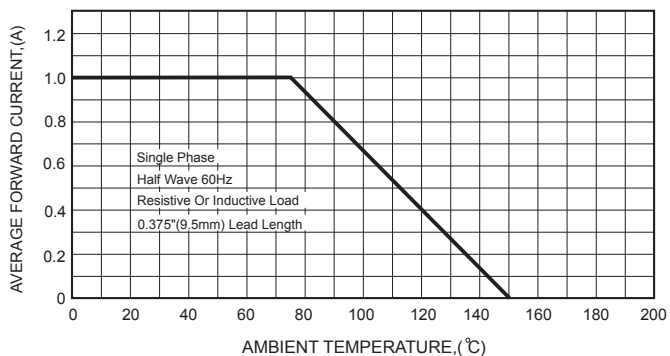


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

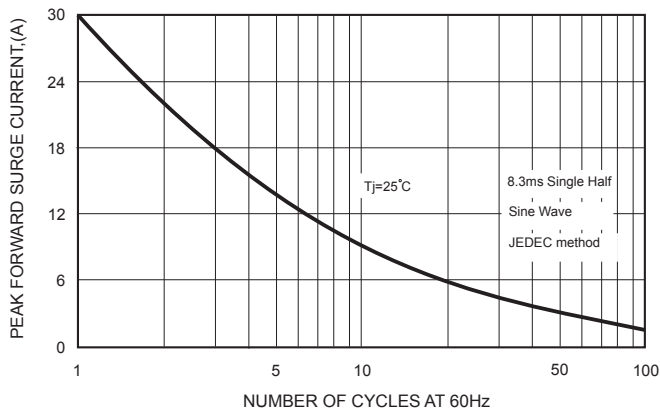


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

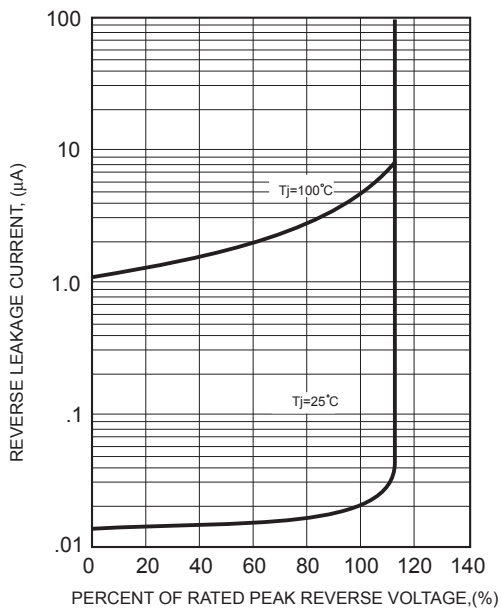


FIG.5-TYPICAL JUNCTION CAPACITANCE

